NSN 5961-01-167-4028

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-167-4028 **Inclosure Material:** Metal **Function For Which Designed:** Rectifier and reverse blocking **Internal Configuration:** Junction contact **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak reverse voltage and 800.0 off-state voltage, peak and 960.0 reverse voltage, peak **Current Rating Per Characteristic:** 225.00 amperes forward current, total rms horsepower metric and 1600.00 amperes forward current, total rms watts **Power Rating Per Characteristic:** 400.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction Shelf Life: N/a **Unit Of Measure: Demilitarization:** No